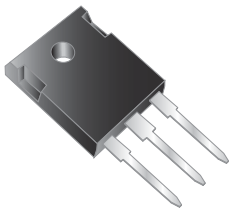
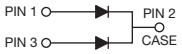
Dual High-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low V_F = 0.54 V at I_F = 5 A

TMBS®



TO-3PW



FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Solder dip 275 °C max. 10 s, per JESD 22-B106
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

RoHS COMPLIANT
HALOGEN FREE

TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters and reverse battery protection.

MECHANICAL DATA

Case: TO-3PW
Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102
M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	2 x 30 A
V_{RRM}	200 V
I_{FSM}	300 A
E_{AS} at L = 60 mH	150 mJ
V_F at I_F = 30 A	0.77 V
T_J max.	150 °C
Package	TO-3PW
Diode variations	Dual common cathode

MAXIMUM RATINGS (T_A = 25 °C unless otherwise noted)				
PARAMETER		**SYMBOL**	**V60200PGW**	**UNIT**
Maximum repetitive peak reverse voltage		V_{RRM}	200	V
Maximum average forward rectified curret (fig. 1)	per device	$I_{F(AV)}$	60	A
	per diode		30	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I_{FSM}	300	A
Non-repetitive avalanche energy at T_J = 25 °C, L = 60 mH per diode		E_{AS}	150	mJ
Peak repetitive reverse current at t_p = 2 µs, 1 kHz, T_J = 38 °C ± 2 °C per diode		I_{RRM}	0.5	A
Voltage rate of change (rated V_R)		dV/dt	10 000	V/µs
Operating junction and storage temperature range		T_J, T_{STG}	-40 to +150	°C

ELECTRICAL CHARACTERISTICS (T_A = 25 °C unless otherwise noted)						
PARAMETER	**TEST CONDITIONS**		**SYMBOL**	**TYP.**	**MAX.**	**UNIT**
Breakdown voltage	I_R = 1.0 mA	T_A = 25 °C	V_{BR}	200 (minimum)	-	V
Instantaneous forward voltage per diode	I_F = 10 A	T_A = 25 °C	V_F (1)	0.69	-	V
	I_F = 15 A			0.90	-	
	I_F = 30 A			1.28	1.48	
	I_F = 10 A	T_A = 125 °C		0.54	-	
	I_F = 15 A			0.66	-	
	I_F = 30 A			0.77	0.85	
Reverse current per diode	V_R = 180 V	T_A = 25 °C	I_R (2)	3.4	-	µA
		T_A = 125 °C		4.6	-	mA
	V_R = 200 V	T_A = 25 °C		-	210	µA
		T_A = 125 °C		7.5	27	mA

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T_A = 25 °C unless otherwise noted)				
PARAMETER		**SYMBOL**	**V60200PGW**	**UNIT**
Typical thermal resistance	per diode	$R_{\theta JC}$	1.5	°C/W
	per device		0.8	

ORDERING INFORMATION (Example)					
PACKAGE	**PREFERRED P/N**	**UNIT WEIGHT (g)**	**PACKAGE CODE**	**BASE QUANTITY**	**DELIVERY MODE**
TO-3PW	V60200PGW-M3/4W	4.5	4W	30/tube	Tube

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

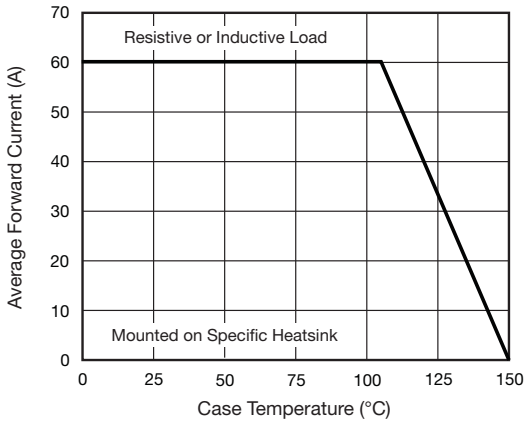


Fig. 1 - Forward Current Derating Curve

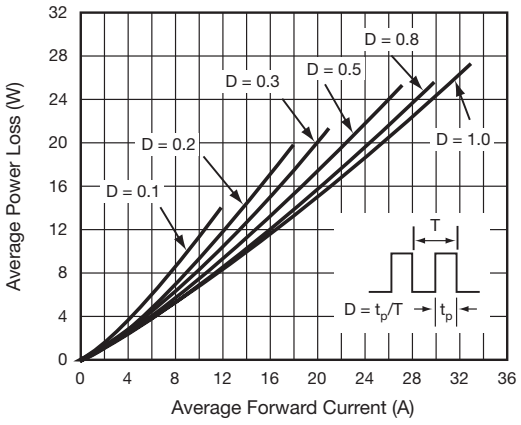


Fig. 2 - Forward Power Loss Characteristics Per Diode

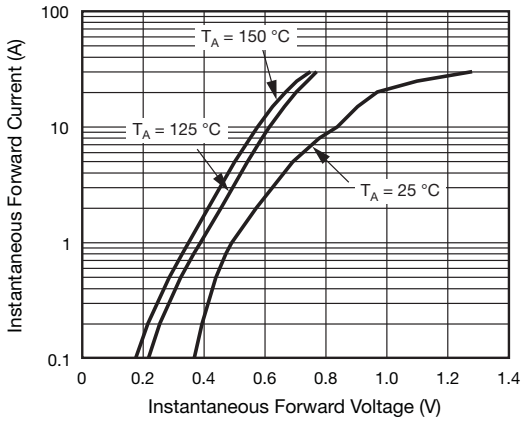


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

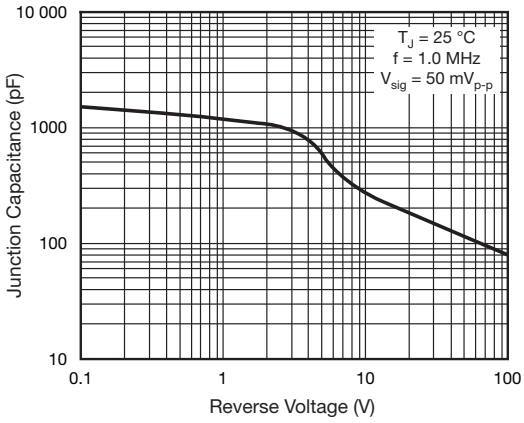


Fig. 5 - Typical Junction Capacitance Per Diode

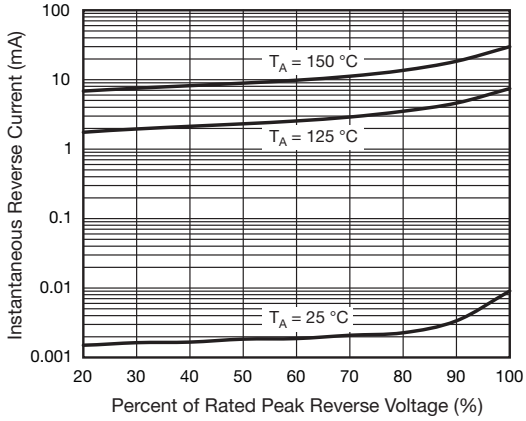


Fig. 4 - Typical Reverse Characteristics Per Diode

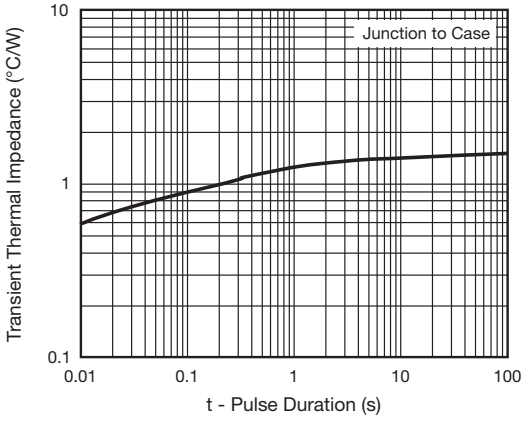
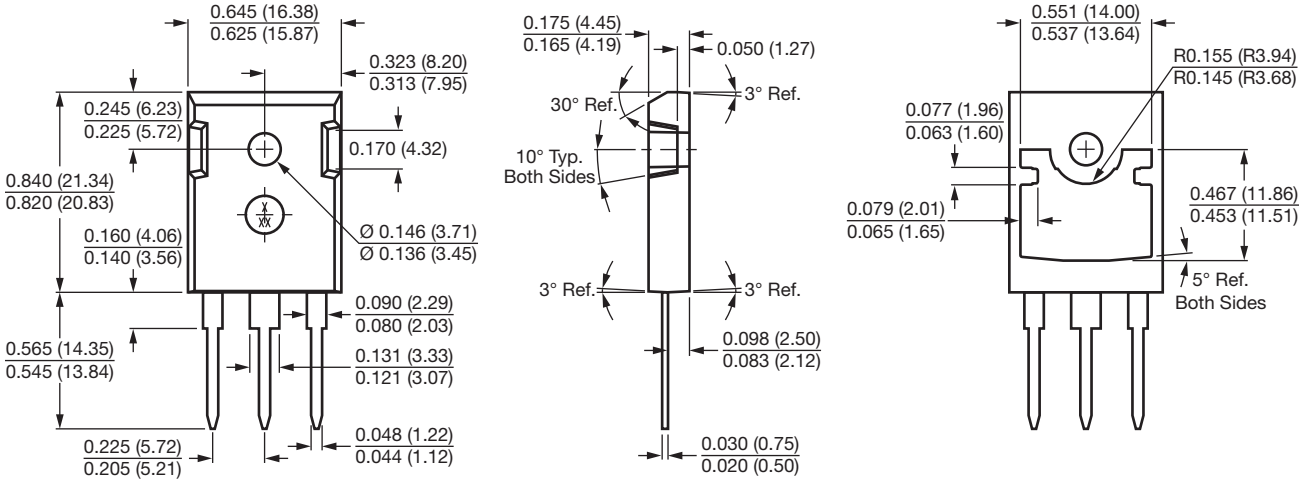


Fig. 6 - Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

TO-3PW



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